



Resonators for Precise Material Measurements

Examples of resonators successfully used by our customers worldwide:

- Split post dielectric resonators for permittivity & loss tangent measurements at 1 GHz .. 35 GHz. Typical uncertainty of permittivity measurement: 0.5%; Resolution of loss tangent measurement: 5x10⁻⁵
- Re-entrant cavities for permittivity & dielectric loss tangent measurements of dielectrics at 50MHz .. 1.2 GHz Typical uncertainty of permittivity measurement: 1% Resolution of loss tangent measurement: 5x10⁻⁵
- 3. **Dielectric resonators** for permittivity and dielectric loss tangent measurement of low loss dielectrics, at 1 .. 10 GHz. Typical uncertainty of permittivity measurement: 0.3% Resolution of loss tangent measurement: 5x10⁻⁶
- 4. **Sapphire resonators** for measurements of surface resistance of metals and superconductors at frequencies 15-25 GHz
- 5. **Dielectric resonators** for complex permeability measurements of low loss ferrites .

High-Power Solid-State Sources

New high power microwave sources, based on solid-state amplifiers in GaAs MESFET CW AB-class attain perfect control of frequency and amplitude. Prototypes developed to date show:

- output power levels up to 200W, controlled within 20dB range,
- efficiency better than 50%,
- output frequency from 2.3..2.6 GHz range, set by a microcontroller with 1MHz accuracy,
- operation in either single fixed-frequency regime, or with self-tuning for best matching, with reflections as weak as -1dB accurately measured,
- feeding by 12V DC supply.

The new sources open up many new applications of microwave power, e.g.:

- microwave-driven chemical reactions,
- precise measurements of material parameters under high-power conditions,
- biological effects under controlled radiation,
- applications where high voltage or high magnetic fields are prohibited.

120 W ISM band GaAs MESFET amplifier



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